

SCHOTTKY BARRIER RECTIFIERS

REVERSE VOLTAGE - 30 to 40 Volts
FORWARD CURRENT - 60 Amperes

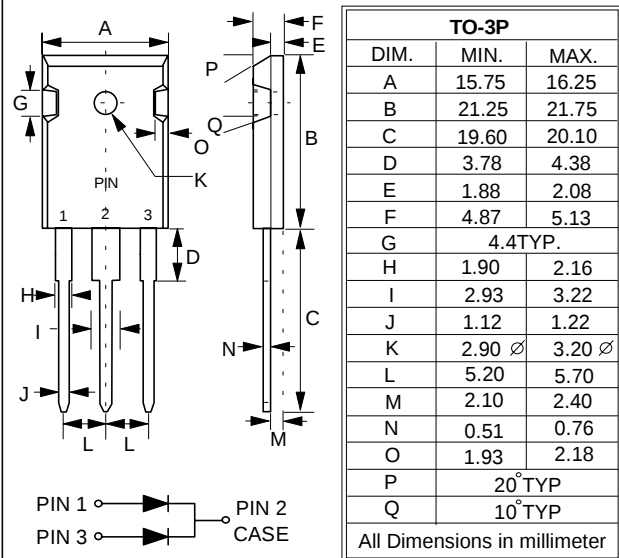
FEATURES

- Metal of silicon rectifier, majority carrier conduction
- Guard ring for transient protection
- Low power loss, high efficiency
- High current capability, low VF
- High surge capacity
- Plastic package has UL flammability classification 94V-0
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications

MECHANICAL DATA

- Case : TO-3P molded plastic
- Polarity : As marked on the body
- Weight : 0.2 ounces, 5.6 grams
- Mounting position : Any

TO-3P



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.
Single phase, half wave, 60Hz, resistive or inductive load.
For capacitive load, derate current by 20%

CHARACTERISTICS	SYMBOL	SBL6030PT	SBL6040PT	UNIT
Maximum Recurrent Peak Reverse Voltage	V _{RRM}	30	40	V
Maximum RMS Voltage	V _{RMS}	21	28	V
Maximum DC Blocking Voltage	V _{DC}	30	40	V
Maximum Average Forward Rectified Current @T _C =100°C	I _(AV)	60		A
Peak Forward Surge Current 8.3ms single half sine-wave superimposed on rated load (JEDEC METHOD)	I _{FSM}	500		A
Maximum forward Voltage at 30A DC @T _J =25°C	V _F	0.55		V
Maximum DC Reverse Current at Rated DC Blocking Voltage @T _J =25°C @T _J =100°C	I _R	10 200		mA
Typical Junction Capacitance per element (Note1)	C _J	1000		pF
Typical Thermal Resistance (Note 2)	R _{θJC}	0.5		°C/W
Operating Temperature Range	T _J	-55 to +125		°C
Storage Temperature Range	T _{STG}	-55 to +150		°C

NOTES : 1. Measured at 1.0MHz and applied reverse voltage of 4.0VDC.
2. Thermal Resistance Junction to Case.

REV. 2, 01-Dec-2000, KTHD13

FIG.1 - FORWARD CURRENT DERATING CURVE

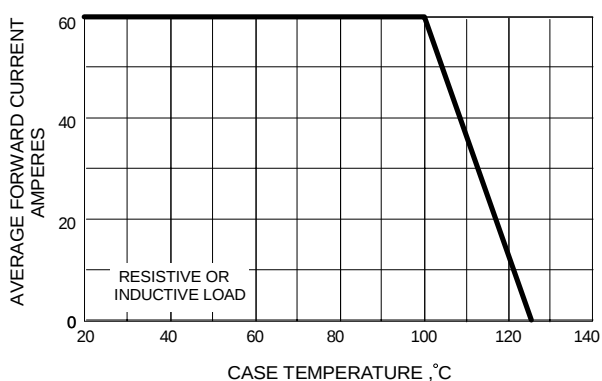


FIG.2 - MAXIMUM NON-REPETITIVE SURGE CURRENT

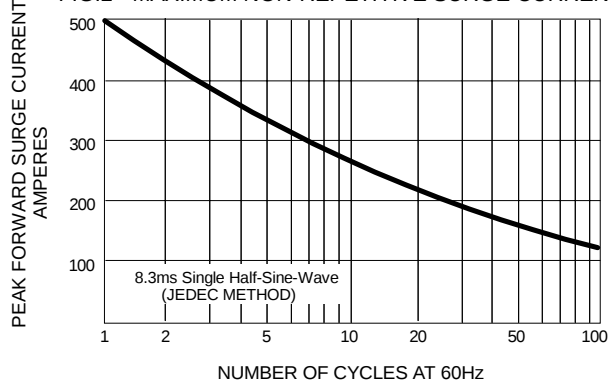


FIG.3 - TYPICAL REVERSE CHARACTERISTICS

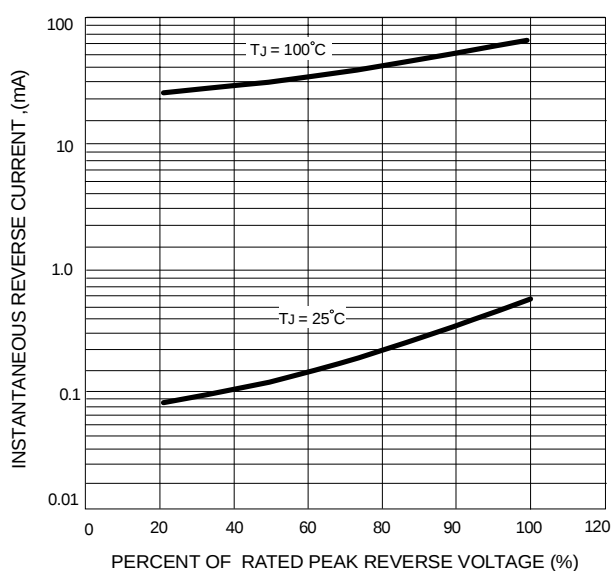


FIG.4 - TYPICAL FORWARD CHARACTERISTICS

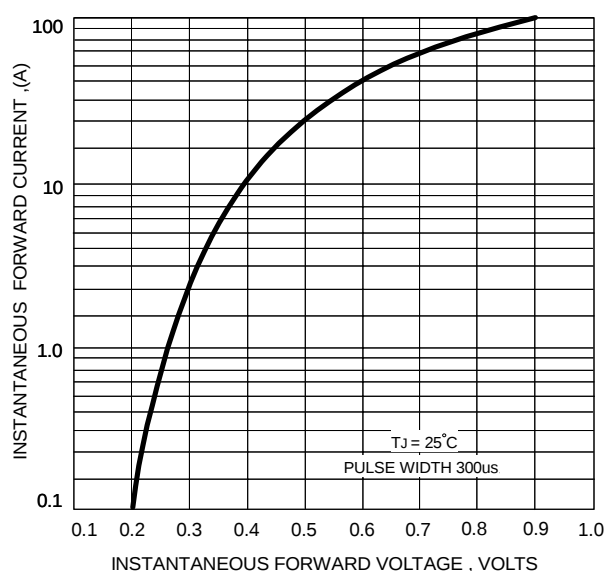


FIG.5 - TYPICAL JUNCTION CAPACITANCE

